

# Thyristor Module

$$\begin{aligned} V_{RRM} &= 1800\text{ V} \\ I_{TAV} &= 300\text{ A} \\ V_T &= 1,02\text{ V} \end{aligned}$$

1~ Triac

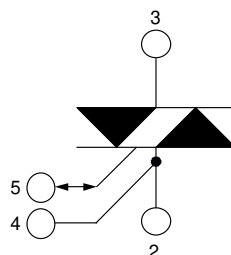
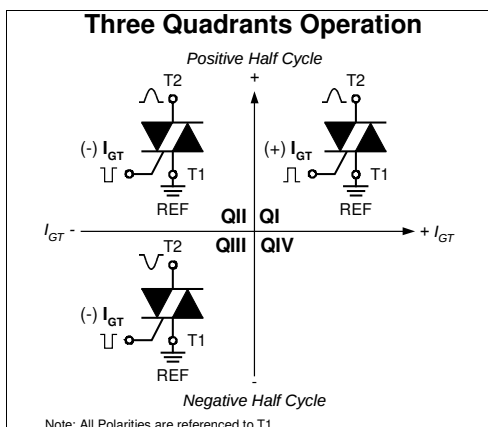
Part number

**MCMA650MT1800NKD**



Backside: isolated

 E72873



## Features / Advantages:

- Triac for line frequency
- Three Quadrants Operation
  - QI - QIII
- Planar passivated chip
- Long-term stability of blocking currents and voltages

## Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

## Package: Y1

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: Copper internally DCB isolated
- Advanced power cycling

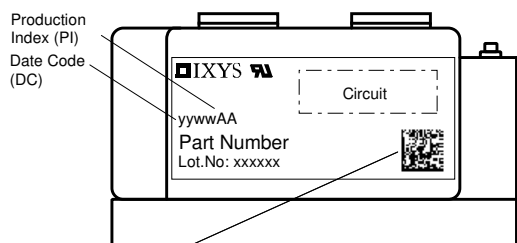
## Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).



| Rectifier      |                                                      |                                                                                                                                                                         |                                | Ratings |      |       |                   |
|----------------|------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|---------|------|-------|-------------------|
| Symbol         | Definition                                           | Conditions                                                                                                                                                              |                                | min.    | typ. | max.  | Unit              |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                           |                                |         |      | 1900  | V                 |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                           |                                |         |      | 1800  | V                 |
| $I_{R/D}$      | reverse current, drain current                       | $V_{R/D} = 1800\text{ V}$                                                                                                                                               | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1     | mA                |
|                |                                                      | $V_{R/D} = 1800\text{ V}$                                                                                                                                               | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 40    | mA                |
| $V_T$          | forward voltage drop                                 | $I_T = 300\text{ A}$                                                                                                                                                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,09  | V                 |
|                |                                                      | $I_T = 600\text{ A}$                                                                                                                                                    |                                |         |      | 1,26  | V                 |
|                |                                                      | $I_T = 300\text{ A}$                                                                                                                                                    | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 1,02  | V                 |
|                |                                                      | $I_T = 600\text{ A}$                                                                                                                                                    |                                |         |      | 1,23  | V                 |
| $I_{TAV}$      | average forward current                              | $T_C = 85^{\circ}\text{C}$                                                                                                                                              | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 300   | A                 |
| $I_{RMS}$      | RMS forward current per phase                        | 180° sine                                                                                                                                                               |                                |         |      | 650   | A                 |
| $V_{T0}$       | threshold voltage                                    | } for power loss calculation only                                                                                                                                       | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 0,81  | V                 |
| $r_T$          | slope resistance                                     |                                                                                                                                                                         |                                |         |      | 0,68  | mΩ                |
| $R_{thJC}$     | thermal resistance junction to case                  |                                                                                                                                                                         |                                |         |      | 0,12  | K/W               |
| $R_{thCH}$     | thermal resistance case to heatsink                  |                                                                                                                                                                         |                                |         | 0,04 |       | K/W               |
| $P_{tot}$      | total power dissipation                              |                                                                                                                                                                         | $T_C = 25^{\circ}\text{C}$     |         |      | 960   | W                 |
| $I_{TSM}$      | max. forward surge current                           | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                        | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 9,60  | kA                |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                       | $V_R = 0\text{ V}$             |         |      | 10,4  | kA                |
|                |                                                      | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                        | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 8,16  | kA                |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                       | $V_R = 0\text{ V}$             |         |      | 8,82  | kA                |
| $I^2t$         | value for fusing                                     | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                        | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 460,8 | kA <sup>2</sup> s |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                       | $V_R = 0\text{ V}$             |         |      | 447,4 | kA <sup>2</sup> s |
|                |                                                      | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                        | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 332,9 | kA <sup>2</sup> s |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                       | $V_R = 0\text{ V}$             |         |      | 323,3 | kA <sup>2</sup> s |
| $C_J$          | junction capacitance                                 | $V_R = 400\text{ V}$ $f = 1\text{ MHz}$                                                                                                                                 | $T_{VJ} = 25^{\circ}\text{C}$  |         | 438  |       | pF                |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30\text{ }\mu\text{s}$                                                                                                                                           | $T_C = 140^{\circ}\text{C}$    |         |      | 120   | W                 |
|                |                                                      | $t_p = 300\text{ }\mu\text{s}$                                                                                                                                          |                                |         |      | 60    | W                 |
| $P_{GAV}$      | average gate power dissipation                       |                                                                                                                                                                         |                                |         |      | 20    | W                 |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 140^{\circ}\text{C}; f = 50\text{ Hz}$ repetitive, $I_T = 900\text{ A}$                                                                                       |                                |         |      | 100   | A/ $\mu\text{s}$  |
|                |                                                      | $t_p = 200\text{ }\mu\text{s}; di_G/dt = 1\text{ A}/\mu\text{s};$<br>$I_G = 1\text{ A}; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 300\text{ A}$                     |                                |         |      | 500   | A/ $\mu\text{s}$  |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V_D = \frac{2}{3} V_{DRM}$<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)                                                                                       | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 1000  | V/ $\mu\text{s}$  |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6\text{ V}$                                                                                                                                                      | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2     | V                 |
|                |                                                      |                                                                                                                                                                         | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | 3     | V                 |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6\text{ V}$                                                                                                                                                      | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 220   | mA                |
|                |                                                      |                                                                                                                                                                         | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | 400   | mA                |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$                                                                                                                                             | $T_{VJ} = 140^{\circ}\text{C}$ |         |      | 0,25  | V                 |
| $I_{GD}$       | gate non-trigger current                             |                                                                                                                                                                         |                                |         |      | 10    | mA                |
| $I_L$          | latching current                                     | $t_p = 30\text{ }\mu\text{s}$                                                                                                                                           | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 200   | mA                |
|                |                                                      | $I_G = 1\text{ A}; di_G/dt = 1\text{ A}/\mu\text{s}$                                                                                                                    |                                |         |      |       |                   |
| $I_H$          | holding current                                      | $V_D = 6\text{ V}$ $R_{GK} = \infty$                                                                                                                                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 150   | mA                |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$                                                                                                                                             | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2     | $\mu\text{s}$     |
|                |                                                      | $I_G = 1\text{ A}; di_G/dt = 1\text{ A}/\mu\text{s}$                                                                                                                    |                                |         |      |       |                   |
| $t_q$          | turn-off time                                        | $V_R = 100\text{ V}; I_T = 300\text{ A}; V_D = \frac{2}{3} V_{DRM}$<br>$di/dt = 10\text{ A}/\mu\text{s}; dv/dt = 50\text{ V}/\mu\text{s}; t_p = 200\text{ }\mu\text{s}$ | $T_{VJ} = 125^{\circ}\text{C}$ |         | 350  |       | $\mu\text{s}$     |

| Package Y1    |                                                              |                      |                                     | Ratings |      |      |      |
|---------------|--------------------------------------------------------------|----------------------|-------------------------------------|---------|------|------|------|
| Symbol        | Definition                                                   | Conditions           |                                     | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current                                                  | per terminal         |                                     |         |      | 600  | A    |
| $T_{VJ}$      | virtual junction temperature                                 |                      |                                     | -40     |      | 140  | °C   |
| $T_{op}$      | operation temperature                                        |                      |                                     | -40     |      | 125  | °C   |
| $T_{stg}$     | storage temperature                                          |                      |                                     | -40     |      | 125  | °C   |
| <b>Weight</b> |                                                              |                      |                                     |         | 650  |      | g    |
| $M_D$         | mounting torque                                              |                      |                                     | 4,5     |      | 7    | Nm   |
| $M_T$         | terminal torque                                              |                      |                                     | 11      |      | 13   | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal |                                     | 16,0    |      |      | mm   |
| $d_{Spb/Apb}$ |                                                              | terminal to backside |                                     | 25,0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 4800    |      |      | V    |
|               |                                                              | t = 1 minute         |                                     | 4000    |      |      | V    |



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

## Part description

M = Module  
 C = Thyristor (SCR)  
 M = Thyristor  
 A = (up to 1800V)  
 650 = Current Rating [A]  
 MT = 1~ Triac  
 1800 = Reverse Voltage [V]  
 N = Three Quadrants operation: QI - QIII  
 KD = Y1-2-CU

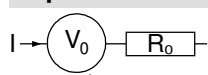
| Ordering | Ordering Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|------------------|--------------------|---------------|----------|----------|
| Standard | MCMA650MT1800NKD | MCMA650MT1800NKD   | Box           | 2        | 518710   |

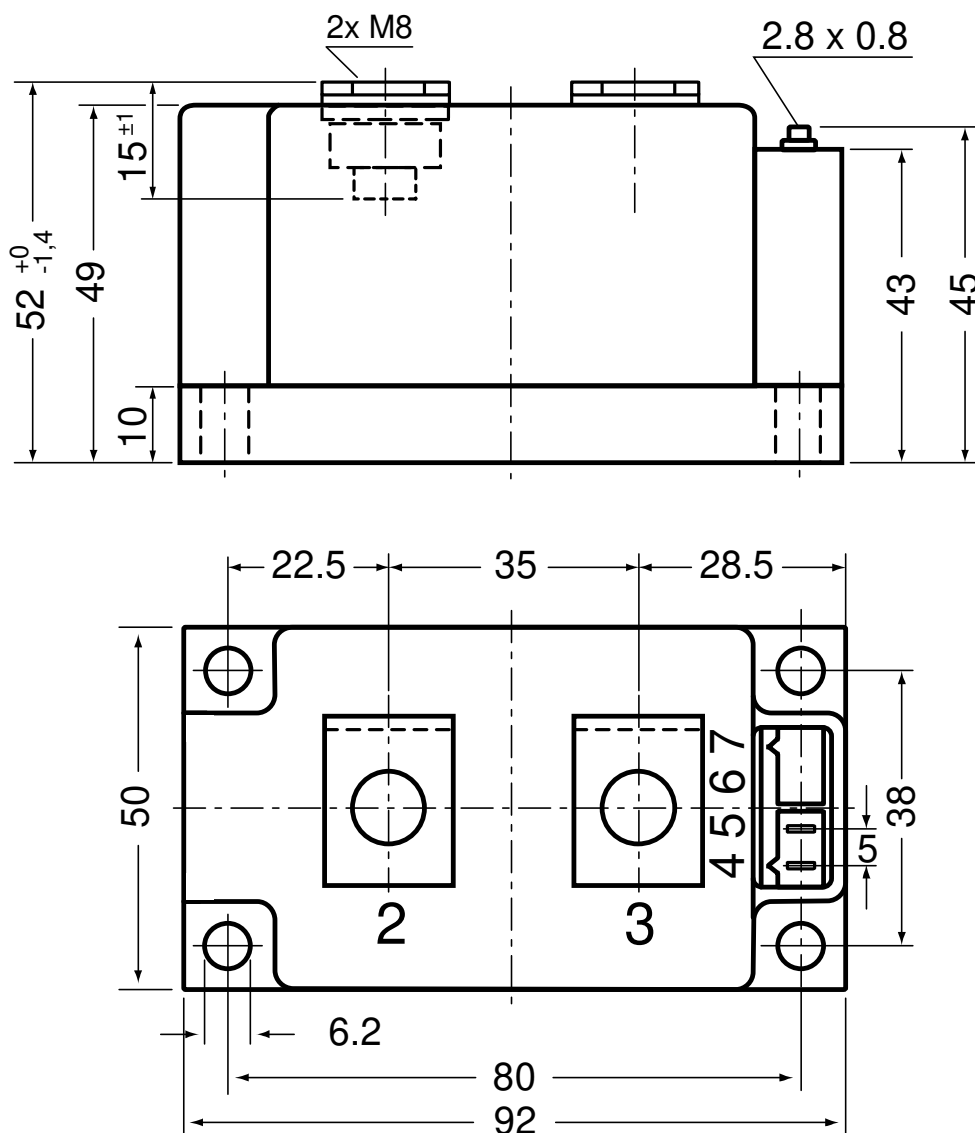
| Similar Part     | Package | Voltage class |
|------------------|---------|---------------|
| MCMA650MT1400NKD | Y1-2-CU | 1400          |

## Equivalent Circuits for Simulation

\* on die level

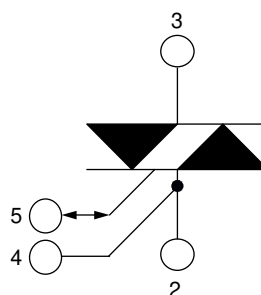
$T_{VJ} = 140^{\circ}\text{C}$

|                                                                                     |                    |                  |    |
|-------------------------------------------------------------------------------------|--------------------|------------------|----|
|  |                    | <b>Thyristor</b> |    |
| $V_{0\ max}$                                                                        | threshold voltage  | 0,81             | V  |
| $R_{0\ max}$                                                                        | slope resistance * | 0,5              | mΩ |

**Outlines Y1**

**Optional accessories for modules**

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red

Type ZY 180L (L = Left for pin pair 4/5) UL 758, style 3751



## Thyristor

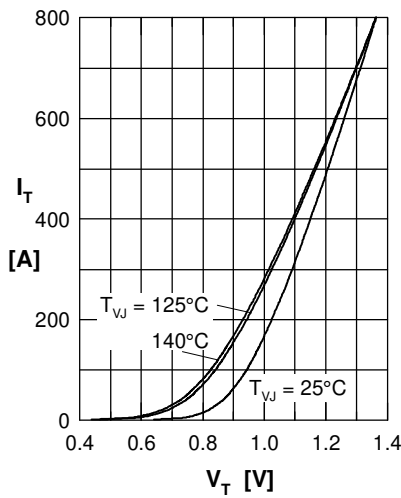


Fig. 1 Forward characteristics

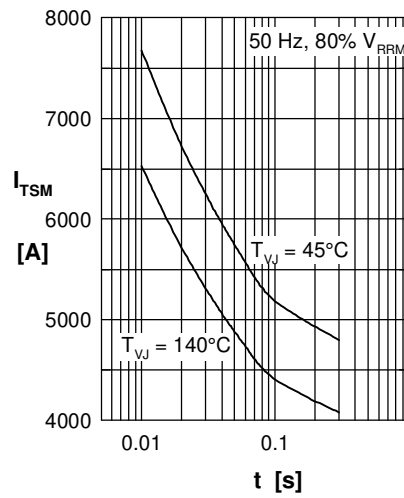


Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

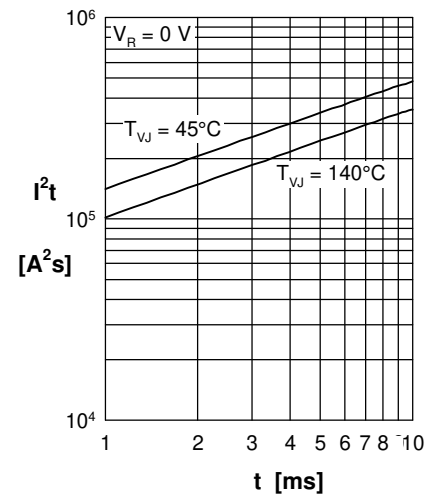


Fig. 3  $I^2t$  versus time (1-10 s)

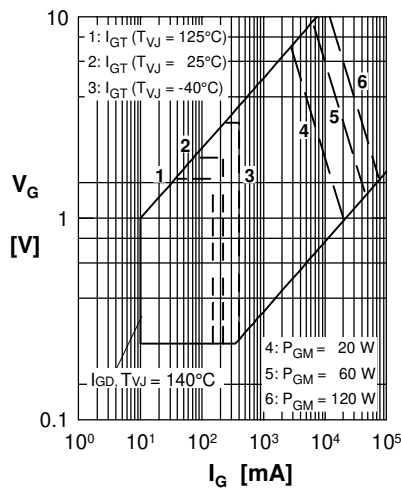


Fig. 4 Gate voltage & gate current

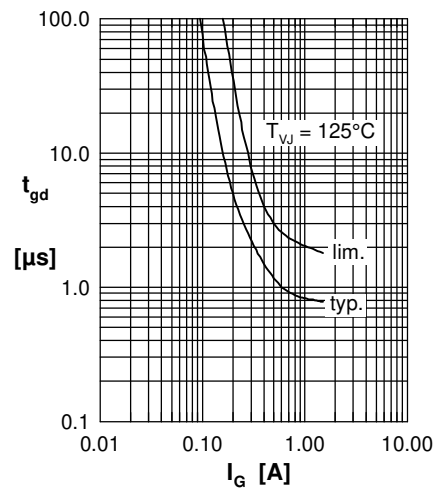


Fig. 5 Gate controlled delay time  $t_{gd}$

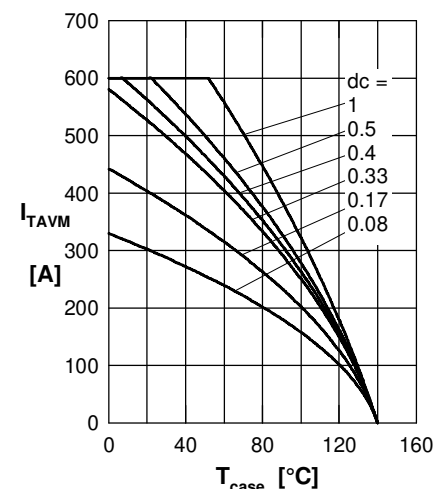


Fig. 6 Max. forward current at case temperature

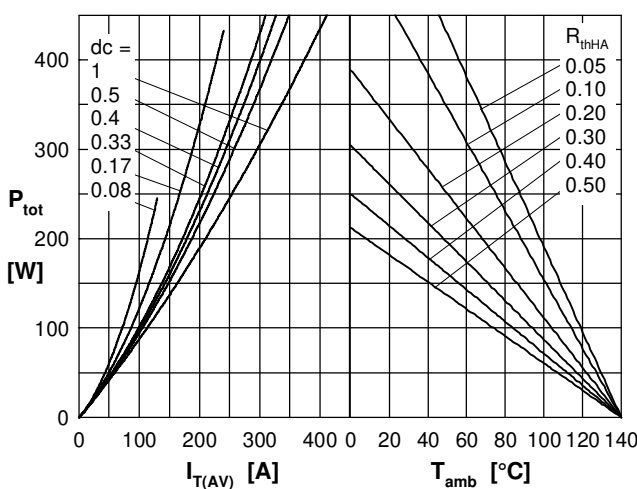


Fig. 7a Power dissipation versus direct output current  
 Fig. 7b and ambient temperature

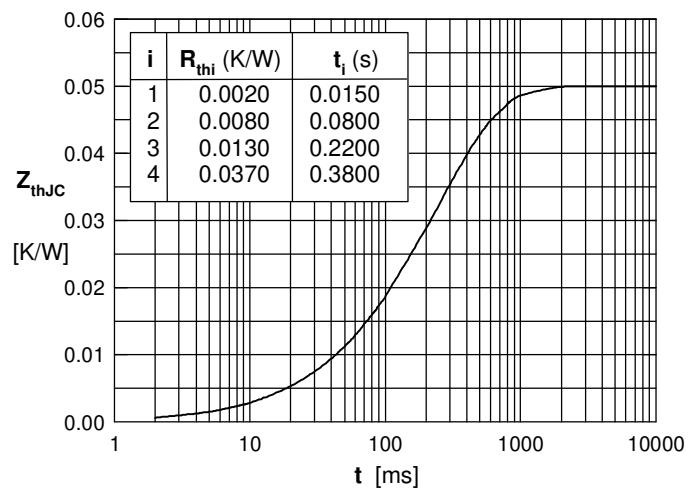


Fig. 8 Transient thermal impedance junction to case